

PJQ4408P

30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

42 A

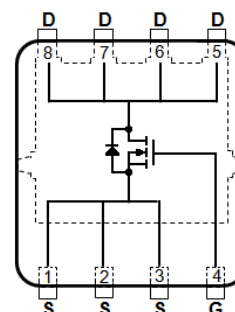
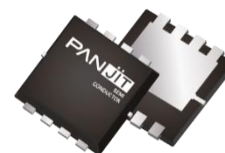
Features

- $R_{DS(ON)}$, $V_{GS}@10V, I_D@16A < 9m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V, I_D@8A < 13m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

DFN3333-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	+20	V
Continuous Drain Current	$T_C=25^{\circ}C$	I_D	42	A
	$T_C=100^{\circ}C$		26	
Pulsed Drain Current ^(Note 1)	$T_C=25^{\circ}C$	I_{DM}	168	
Power Dissipation	$T_C=25^{\circ}C$	P_D	35	W
	$T_C=100^{\circ}C$		14	
Continuous Drain Current	$T_A=25^{\circ}C$	I_D	10	A
	$T_A=70^{\circ}C$		8	
Power Dissipation	$T_A=25^{\circ}C$	P_D	2.0	W
Power Dissipation	$T_A=70^{\circ}C$		1.3	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^{\circ}C$
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{\theta JC}$	3.6	$^{\circ}C/W$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0	1.7	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =16A	-	6.2	9	mΩ
		V _{GS} =4.5V, I _D =8A	-	9.6	13	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =15V, I _D =20A, V _{GS} =4.5V ^(Note 2,3)	-	7.1	-	nC
Gate-Source Charge	Q _{gs}		-	3.1	-	
Gate-Drain Charge	Q _{gd}		-	2.0	-	
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	763	-	pF
Output Capacitance	C _{oss}		-	132	-	
Reverse Transfer Capacitance	C _{rss}		-	81	-	
Turn-On Delay Time	t _{d(on)}	V _{DS} =15V, I _D =15A, V _{GS} =10V, R _G =6Ω ^(Note 2,3)	-	5.4	-	ns
Turn-On Rise Time	t _r		-	86	-	
Turn-Off Delay Time	t _{d(off)}		-	20	-	
Turn-Off Fall Time	t _f		-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	42	A
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.7	1.0	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics
3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J = 25°C.
4. The maximum current rating is package limited
5. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

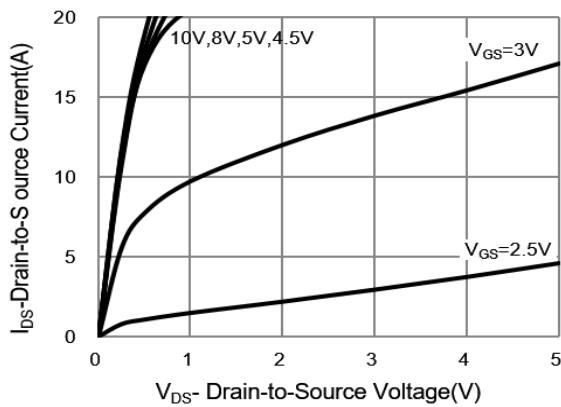


Fig.1 On-Region Characteristics

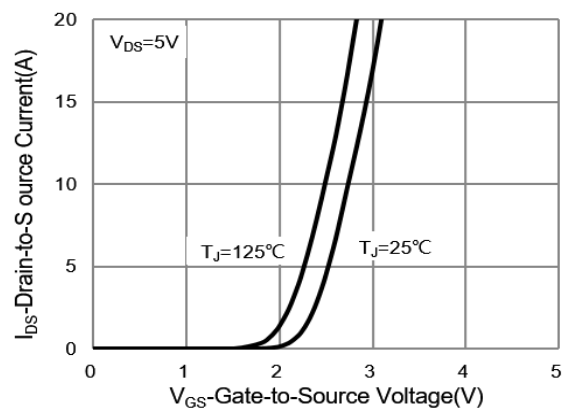


Fig.2 Transfer Characteristics

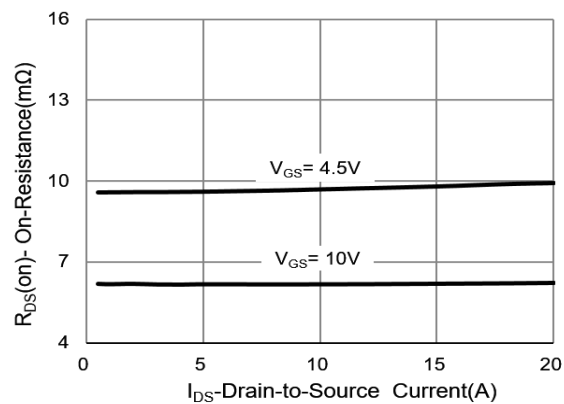


Fig.3 On-Resistance vs. Drain Current

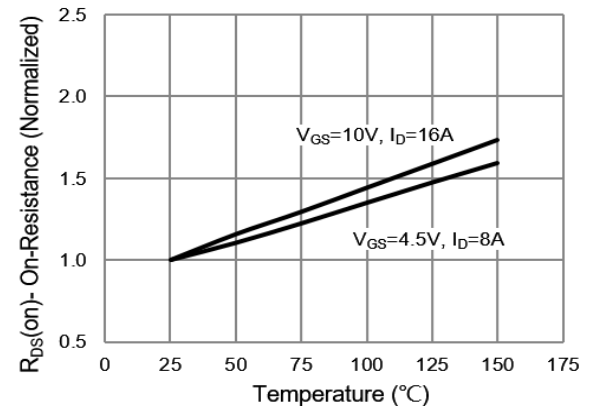


Fig.4 On-Resistance vs. Junction temperature

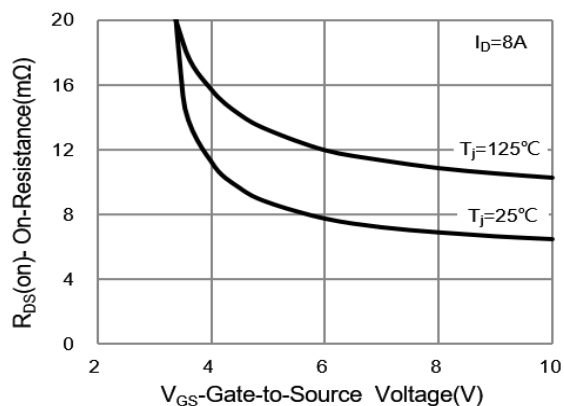


Fig.5 On-Resistance Variation with V_{GS} .

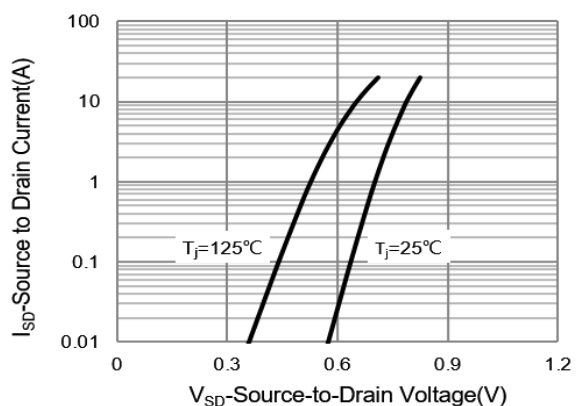
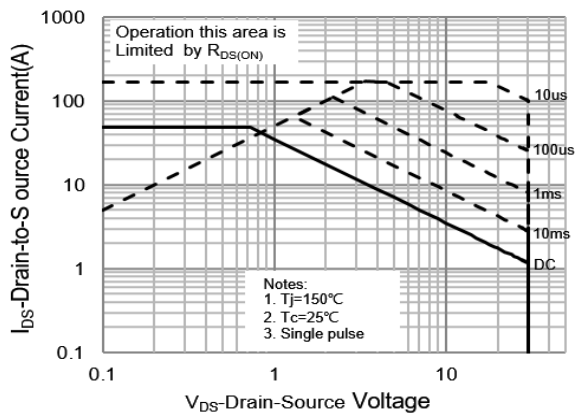
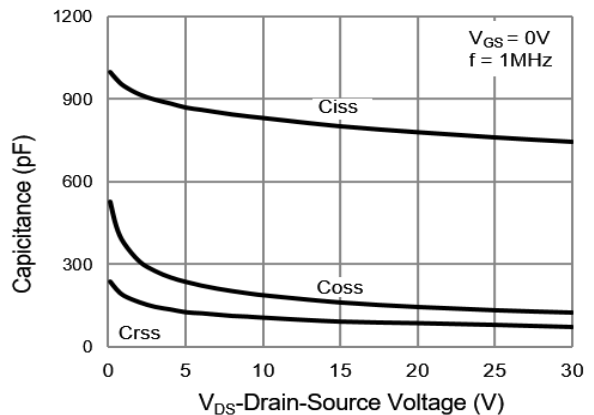
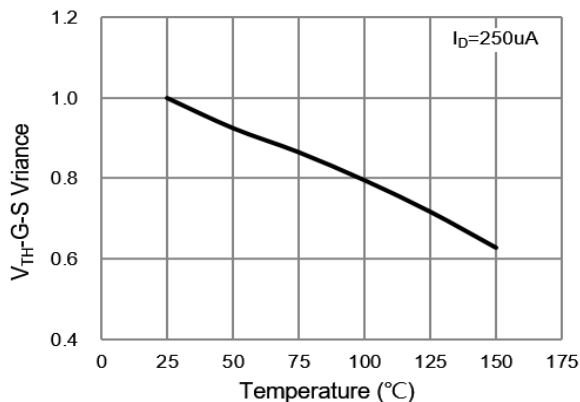
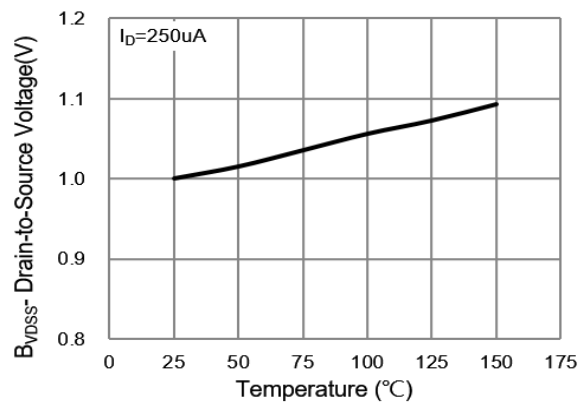
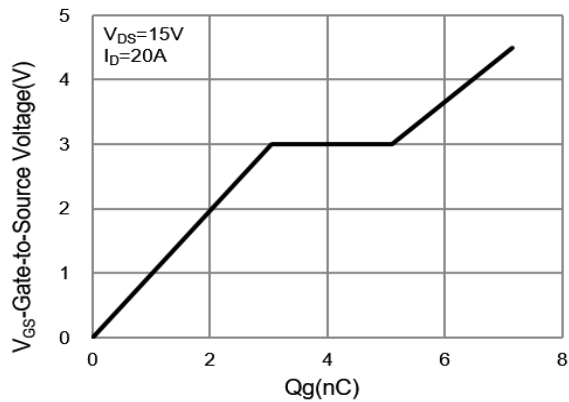


Fig.6 Source-Drain Diode Forward Voltage

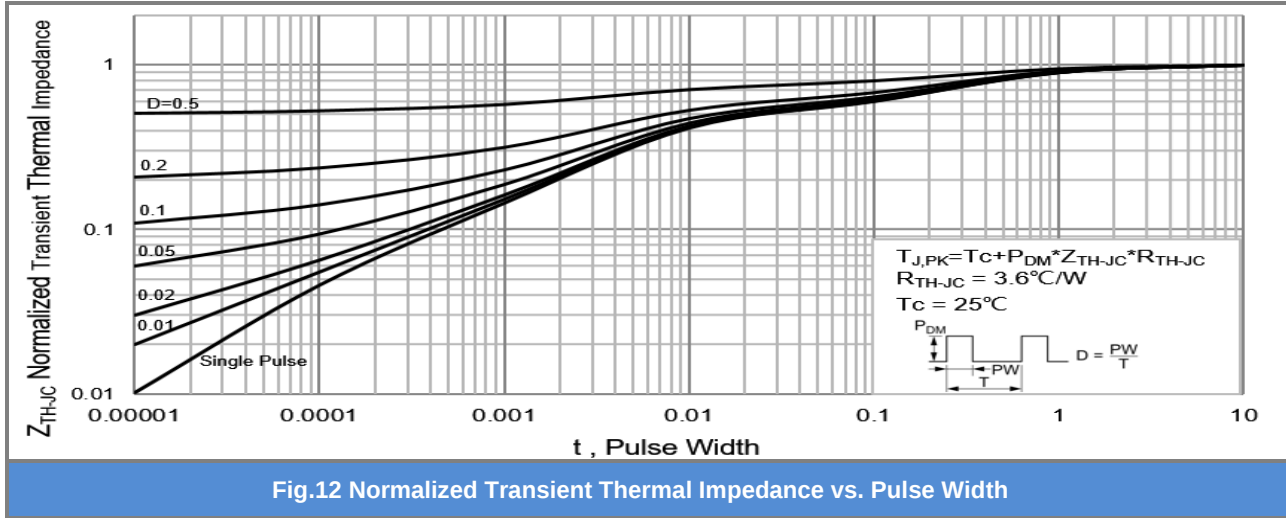
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TYPICAL CHARACTERISTIC CURVES



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TYPICAL CHARACTERISTIC CURVES

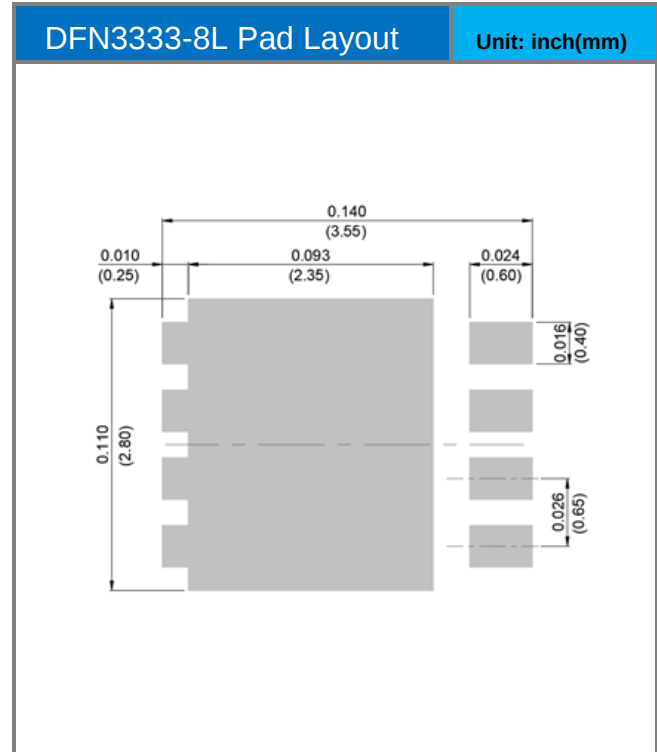
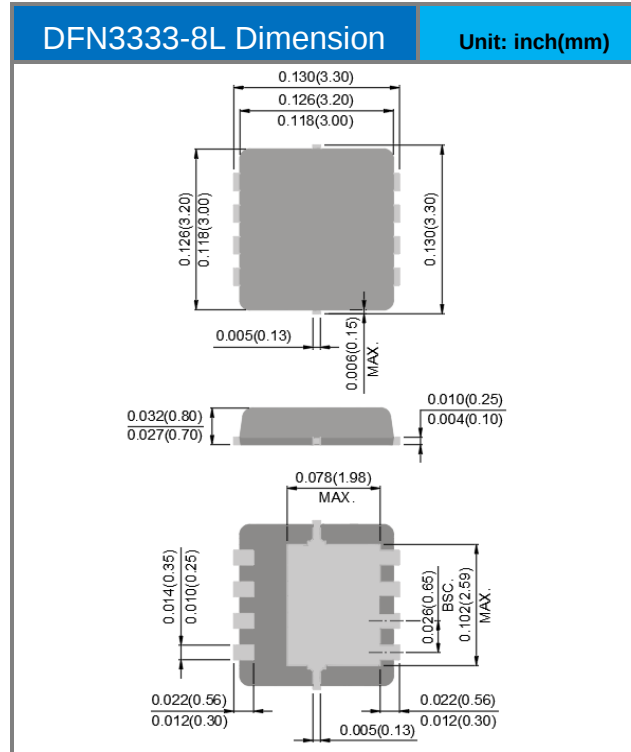


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Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4408P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4408	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout



PJQ4408P

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